



Bipolar NPN Bare Die – BTN980

Part Description

The BTN980 is a silicon BJT transistor available in bare die form and well suited for use in High Voltage Switching applications.

Key Parameters:

- VCBO = 1600V
- VCEO = 800V
- VEBO = 6V
- hFE = 20-40 @ VCE = 5V, IC = 0.01A
- VCE(Sat) = 0.3V @ IC = 0.2A, IB = 40mA
- fT = - MHz @ VCE = - V, IE = - A
- COBO = - pF @ VCB = - V

Features

Die Size (Unseen)

2000 μ m X 2000 μ m, 79 Mils X 79 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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